NON-CROSSING APPROXIMATION STUDY OF MULTI-ORBITAL KONDO EFFECT IN QUANTUM DOT SYSTEMS

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W e study the three-orbital K ondo e ect in quantum dot (Q D) systems by applying the non-crossing approximation to the three-orbital A nderson in purity model. By investigating the tunneling conductance through a Q D, we show that the competition between the H und-coupling and the orbital level-splitting gives rise to characteristic behavior in transport properties. It is found that the H und-coupling becomes more important in the three-orbital case than in the two-orbital case. We also show that the enhancement of K ondo temperature due to the singlet-triplet mechanism suggested for the two-orbital m odel tends to be suppressed by the existence of the third orbital.

1. Introduction

E lectron transport properties in nanoscale systems have been studied extensively. In particular, recent progress in nanofabrication enables us to observe the correlation e ect due to the orbital degrees of freedom in highly-symmetric quantum dot (QD) systems. In these systems, not only ordinary spin K ondo e ect but also various orbital K ondo e ects, such as SU (4) K ondo e ect in a carbon nanotube QD,¹ singlet-triplet K ondo e ect², etc., have been observed. These observations of orbital K ondo e ects in QD systems have activated theoretical works for orbital K ondo e ects. Theoretical studies using the two-orbital A nderson in purity m odel (A IM) ^{3;4;5;6;7} have pointed out the importance of orbital degreeracy; (i) W hen one electron occupies two nearly-degenerate orbital-levels, the K ondo tem perature T_K gets enhanced as the system approaches to the SU (4) symmetric point where two orbitals are degenerate. (ii) W hen two electrons occupy two orbital-levels, the ground state of the isolated A nderson in purity from conduction electrons is the triplet (spin S = 1) for degenerate energy levels of two orbitals. W hen the level-splitting

" becomes larger, the ground state changes into the singlet. As "increases, $T_K\,$ takes a maximum at the point where the energy levels of the two states are degenerate.

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In contrast to the detailed investigation of the two-orbital case, the three-orbital K ondo e ect in QD systems has not been su ciently understood yet. Experim entally, the three-orbital K ondo e ect has been realized in the vertical QD⁸, where the orbital degeneracy is well controlled by an external magnetic eld or deformation of the QD⁹. Therefore, it is desirable to study transport properties via the three-orbital K ondo e ect by system atically changing orbital degeneracy in the three-orbital A M.

In this paper, we study the three-orbital K ondo e ect by applying the noncrossing approximation $(NCA)^{10}$ to the three-orbital A M. We focus on the K ondo e ect for integer lling; two or three electrons occupy three orbitals. By investigating the tunneling conductance through a QD, we show that the competition between the H und-coupling and the orbital level-splitting gives rise to characteristic transport properties. It is found that the H und-coupling becomes more important in the three-orbital case than in the two-orbital case. We also show that the enhancement of T_K due to the singlet-triplet mechanism suggested for the two-orbital m odel tends to be suppressed by the existence of the third orbital.

This paper is organized as follows. In the next section, we brie y mention the model and method. In Sec. 3, we show the numerical results, and discuss the characteristic transport properties due to the three-orbitalK ondo e ect in comparison with the two-orbital case. Brief summary is given in Sec. 4.

2. M odeland M ethod

We study the three-orbitalK ondo e ect by exploiting the three-orbitalAM,

$$H = H_{c} + H_{loc} + H_{m ix};$$

$$H_{c} = \mathbf{W}_{k} C_{ki}^{v} c_{ki};$$

$$H_{loc} = \sum_{k = d_{i}}^{ki} C_{ki}^{v} d_{i} + U \sum_{n_{d_{i}}, n_{d_{i}} + U^{0}}^{X} n_{d_{i}} n_{d_{j}0} J \sum_{(i \in j)}^{X} S_{d_{i}} S_{j};$$

$$H_{m ix} = \sum_{ki}^{i} V_{ki} c_{ki}^{v} d_{i} + H x:;$$
(1)

where H_c , H_{bc} , and H_{mix} describe a part of conduction electrons in the leads, a QD, and mixing between the leads and the QD, respectively. Here, q_{ki} (d_i) annihilates a conduction electron (localized electron in the QD) with spin in the orbital i, and $n_{d_i} = d_i^y d_i \cdot S_{d_i}$ is the spin operator for a localized electron in the orbital i. E_{d_i} denotes the local level of the orbital i, U (U⁰) the intraorbital (interorbital). C oulom b interaction and J denotes the H und-coupling am ong orbitals.

To analyze our model (1), we use the NCA.¹⁰ By calculating the local density of states $_{i}$ (!), we obtain the tunneling conductance G through the QD,¹¹

$$G = \frac{e^2}{2} d! \frac{df(!)}{d!} \frac{X}{i} (!); \qquad (2)$$

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where denotes the strength of the hybridization between conduction electrons and localized electrons in the QD, and f(!) is the Ferm i distribution function.

3. Num erical R esults

W e address the case where three electrons occupy three orbitals in the QD (referred as the case of three electrons in three orbitals), and the case where two electrons occupy three orbitals in the QD (referred as the case of two electrons in three orbitals). We especially focus on the competition between the Hund-coupling J and the orbital level-splitting ". We set $U = U^0$ in the following calculation and use in units of the energy.

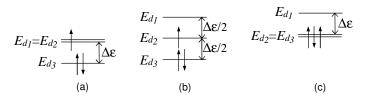


Figure 1. Three types of the orbital splitting. (a) $E_{d_1} = E_{d_2} = E_{d_3} + ", (b) E_{d_1} = E_{d_2} + "=2; E_{d_3} = E_{d_2}$ "=2, (c) $E_{d_1} = E_{d_2} + " = E_{d_3} + ". The electron lling is assumed to be unchanged due to ".$

We rst investigate the orbital K ondo e ect for the case of three electrons in three orbitals. We consider three types of the orbital splitting shown in Fig. 1. In large " limit for each type of the orbital splitting, it is expected that (a) SU (4) K ondo e ect, (b) SU (2) K ondo e ect, and (c) SU (4) K ondo e ect with three electrons are realized, respectively. Let us start our discussion for the results without H und-coupling. In Fig. 2 (a), we plot the tunneling conductance G as a function of

" for each type of the orbital splitting in Fig.1. The conductance of (a) and (c) types results in the same behavior because of particle-hole symmetry. For each type of the orbital splitting, G m onotonically decreases as "increases. The reduction of the orbital degeneracy due to "lowers $T_{\rm K}$, which yields the decrease in G. For large "("= > 0.4), G of (a) and (c) types is larger than G of (b) type. This behavior is consistent with the fact that $T_{\rm K}$ in SU (4) K ondo e ect is higher than $T_{\rm K}$ in SU (2) K ondo e ect, although G in both cases take the same value at zero tem perature.¹²

We next show the results including the elects of the Hund-coupling J in Fig.2 (b). For comparison, we plot the result for the case of two electrons in two orbitals. Each conductance exhibits a maximum structure, which is due to the competition between the Hund-coupling and the level-splitting. For detailed explanation, we describe the ground state of H_{loc}. For the nite Hund-coupling J, the ground state is the spin S = 3=2 state (quartet state) at "= 0. When the orbital splitting is

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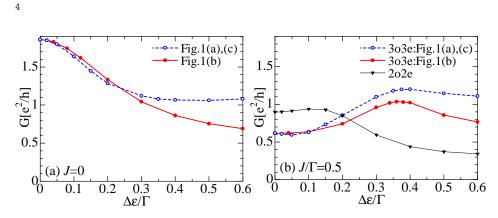


Figure 2. The conductance G as a function of the level-splitting " for the case of three electrons in three orbitals (a) without H und-coupling J = 0, (b) with H und-coupling J = 0.5. P aram eters are set as $U = U^{0} = 10$ and T = 0.05. The types of the orbital splitting as shown in Fig. 1 (a) and (c) (dashed line), and Fig. 1 (b) (thick solid line) are considered. For com parison, we plot the result for the case of two electrons in two orbitals for the same parameters (thin solid line).

introduced as shown in Fig. 1(a), the ground state changes into the quartet state with fourfold degeneracy of the spin and orbital degrees of freedom at large ", where the SU (4) K ondo e ect is induced, as mentioned above. On the other hand, when the orbital splitting is introduced as shown in Fig. 1(b), the ground state changes from the S = 3=2 quartet state to the doublet state with the spin " and # degrees of freedom, which leads to the ordinary SU (2) K ondo e ect. At the critical point where the ground state changes as shown in Fig. 3, the degeneracy of the ground state is enlarged, which gives rise to the enhancement of the K ondo tem perature. A ctually, as " increases, the conductance G in Fig. 2(b) take a maximum near the critical point. N ote that G for the case of Fig. 1(a) is somewhat larger than that of Fig. 1(b) near the critical point, because the degeneracy for the case of Fig. 1(a) is larger than that of Fig. 1(b). The mechanism of the maximum structure of G is similar to the singlet-triplet K ondo e ect, which occurs in the

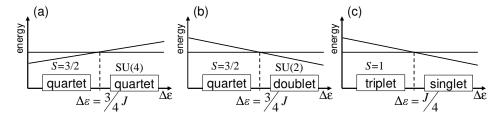


Figure 3. Schem atic diagram for the change of the ground state of H $_{\rm loc}$ with nite J and ". (a) Orbital splitting is introduced as shown in Fig.1 (a). (b) Orbital splitting is introduced as shown in Fig.1 (b). (c) The case of two electrons in two orbitals.

case of two electrons in two orbitals. The di erence appears at the point where T_K is enhanced; In the three-orbital case, T_K is enhanced at " $\frac{3}{4}J$, while T_K is enhanced at " $\frac{1}{4}J$ in the two-orbital case. This indicates that the e ect of J remains even at larger " in the three-orbital case, because three electrons gain more H und-coupling energy than two electrons. Namely, the H und-coupling becomes more in portant in the three-orbital case than in the two-orbital case.

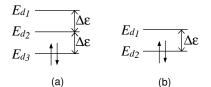


Figure 4. (a) Level-splitting of three orbitals. $E_{d_1} = E_{d_2} + "; E_{d_3} = E_{d_2}$ ". (b) Level-splitting of two orbitals. $E_{d_1} = E_{d_2} + "$. The electron lling is assumed to be unchanged due to ".

We now turn to the case of two electrons in three orbitals. Here, we discuss how the third orbital a lects the transport properties, by comparing the results to those for the case of two electrons in two orbitals. We consider the level-splitting " as shown in Fig. 4. In Fig. 5(a), we plot the tunneling conductance G as a function of the level-splitting " for the case of two electrons in three orbitals and the case of two electrons in two orbitals without H und-coupling. As " increases,

G in both cases decreases m onotonically, and approaches the same value. At large " ("= > 0.4), the orbital with the highest energy-level does not contribute to

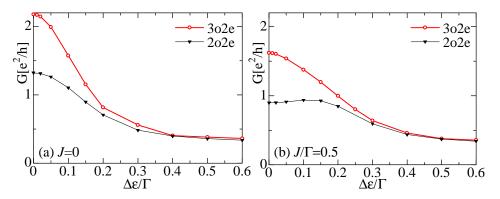


Figure 5. The conductance G for the case of two electrons in three orbitals (302e: thick solid line) and the case of two electrons in two orbitals (202e: thin solid line) as a function of level-splitting " for $U = U^0 = 10$; T = 0.05. We show the results (a) without H und-coupling (J = 0) and (b) with nite H und-coupling J = 0.5.

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the conductance so that G results in the same value.

For the nite H und-coupling J = 0.5, we not the noticeable di erence between the two-and three-orbital cases. As shown in Fig. 5 (b), for the two-orbital case, the H und-coupling J leads to a hump structure with a maximum around "= 0:12, which is due to the singlet-triplet K ondo e ect. On the other hand, for the threeorbital case, the conductance G is not enhanced but m onotonically decreases, as

"increases. For small ", the ground state of H $_{\rm loc}$ is the triplet state, and then it changes into the singlet state. Therefore, it is expected that G gets enhanced due to the singlet-triplet K ondo e ect at interm ediate ". How ever, for the three-orbital case without ", the ground state of H $_{\rm loc}$ has ninefold degeneracy, which gives very high K ondo tem perature. In this case, for small ", the naively expected S = 1 K ondo e ect is not realized but the K ondo e ect with high $\frac{T}{K}$ similar to that without "occurs. Therefore, the enhancem ent of T_K due to the singlet-triplet m echanism m erges into decrease of T_K due to the collapse of the ninefold degenerate K ondo e ect, which m akes di cult to see the singlet-triplet K ondo e ect.

4. Sum m ary

We have studied the three-orbital K ondo e ect in QD systems by exploiting the three-orbital A IM .By means of NCA, we have calculated the tunneling conductance through the QD.We have found that the H und-coupling becomes more in portant in the three-orbital case than in the two-orbital case. We have also shown that the enhancement of T_K due to the singlet-triplet mechanism tends to be suppressed by the existence of the third orbital. It is expected that the characteristic behavior of the tunneling conductance obtained here will be observed experimentally in the near future.

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References

- 1. P.Jarillo-Herrero, J.Kong, H.S.J.van der Zant, C.Dekker, L.P.Kouwenhoven, and S.De Franceschi, Nature (London) 434, 484 (2005).
- 2. S.Sasaki, S.DeFranceschi, J.M. Elzerman, W.G. van der Wiel, M. Eto, S.Tarucha, and L.P.Kouwenhoven, Nature (London) 405, 764 (2000).
- 3. M. Eto, J. Phys. Soc. Jpn. 74, 95 (2005).
- 4. M . Pustilnik and L. I. G lazm an, Phys. Rev. B 64, 045328 (2001).
- 5. W .Hofstetter and H. Schoeller, Phys. Rev. Lett. 88, 016803 (2002).
- 6. W . Izum ida, O . Sakai, and S. Tarucha, Phys. Rev. Lett. 87, 216803 (2001).
- 7. M.S.Choi, R.Lopez, and R.Aguado, Phys. Rev. Lett. 95, 067204 (2005).
- 8. S.Tanucha, D.G. Austing, S. Sasaki, Y. Tokura, W. van der W iel, and L.P.Kouwenhoven, Appl. Phys. A 71, 367 (2000).

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9. Y. Tokura, S. Sasaki, D. G. Austing, and S. Tarucha, Physica B 298, 260 (2001).

- 10. N.E.Bickers, Rev. M od. Phys. 59, 845 (1987).
- 11. Y.Meir and N.S.W ingreen, Phys. Rev. Lett. 68, 2512 (1992).
- 12. R.Sakano and N.Kawakami, Phys. Rev. B 73, 155332 (2006).